NSN 5961-01-333-8515

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View Online at https://aerobasegroup.com/nsn/5961-01-333-8515 **Inclosure Material:** Metal **Overall Length:** Between 6.1 millimeters and 6.6 millimeters **Terminal Length:** Between 38.1 millimeters and 41.3 millimeters **Overall Diameter:** Between 9.1 millimeters and 9.4 millimeters **End Application:** 5865-01-188-3309 jamming system, communications, general utility **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 5.08 millimeters **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 70.0 collector to base voltage/static/emitter open and 45.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 800.0 milliwatts small-signal input power, common-collector preset **Transfer Ratio:** 25.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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